

# SHANGHAI SUNRISE ELECTRONICS CO., LTD.

# SS22A THRU SS26A

SURFACE MOUNT SCHOTTKY **BARRIER RECTIFIER** 

**TECHNICAL SPECIFICATION** 

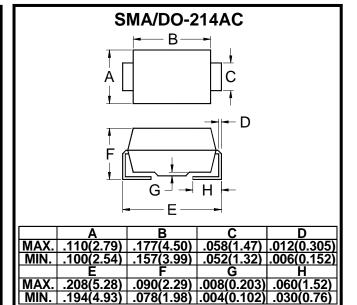
**VOLTAGE: 20 TO 60V CURRENT: 2.0A** 

#### **FEATURES**

- · Ideal for surface mount pick and place application
- Low profile package
- · Low power loss, high efficiency
- High current capability, low V<sub>F</sub>
- High surge capability
- High temperature soldering guaranteed: 260°C/10sec/at terminal

### **MECHANICAL DATA**

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: Molded with UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Color band denotes cathode



Dimensions in inches and (millimeters)

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	SS22A	SS23A	SS24A	SS25A	SS26A	UNITS
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	20	30	40	50	60	V
Maximum RMS Voltage	$V_{RMS}$	14	21	28	35	42	V
Maximum DC Blocking Voltage	$V_{DC}$	20	30	40	50	60	V
Maximum Average Forward Rectified Current $(T_L=100^{\circ}C)$	I <sub>F(AV)</sub>	2.0					Α
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	I <sub>FSM</sub>	50					Α
Maximum Instantaneous Forward Voltage (at rated forward current)	V <sub>F</sub>	0.5 0.7				.7	V
Maximum DC Reverse Current $T_a=25^{\circ}$ C (at rated DC blocking voltage) $T_a=100^{\circ}$ C	I D	0.5 10.0					mA mA
Typical Junction Capacitance (Note 1)	$C_J$		200				
Typical Thermal Resistance (Note 2)	$R_{\theta}(ja)$	25					°C/W
Storage and Operation Junction Temperature	$T_{STG},T_{J}$	-65 to +150					°C
Note:							

- 1.Measured at 1.0 MHz and applied voltage of  $4.0V_{\rm dc}$
- 2.Thermal resistance from junction to terminal mounted on 5x5mm copper pad area

http://www.sse-diode.com